

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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FEATURES

- Advanced non multiplier VCXO Design for High Performance Crystal Oscillators
- Input/Output Range: 150MHz to 160MHz
- Phase Noise Optimized for 155.52MHz:
 -68dBc @10Hz, -152dBc @100kHz
- Very low Phase Jitter: <100fs RMS
- High Pull Range: ±100ppm
- Linearity: <5%
- Integrated Variable Capacitors
- Complementary LVPECL Outputs
- Power Supply: 3.3V ±10%
- Available in Die or Wafer Form

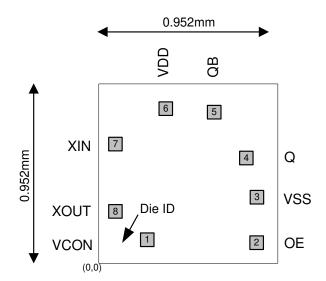
DESCRIPTION

The PL586-55/-58 is a non-multiplier VCXO IC specifically designed to pull fundamental mode crystals from 150MHz to 160MHz. This IC achieves a typical pull range of ±100ppm with <5% linearity. The phase noise performance is optimized for close-in performance and with <100fs phase jitter, makes this an ideal solution for all high end clocking applications such as SONET, WiMax, CPRI, OBSAI, Fiber Channel, and any application where performance and quality are required.

DIE SPECIFICATIONS

Name	Value
Size	952 micron x 952 micron
Reverse side	GND
Pad dimensions	80 micron x 80 micron
Thickness	8 mil

DIE CONFIGURATION



OUTPUT ENABLE LOGIC PL586-55

OE State (Pad 4)	Output Buffers State
0	Outputs Tri-Stated
1 (Default)	Outputs Enabled

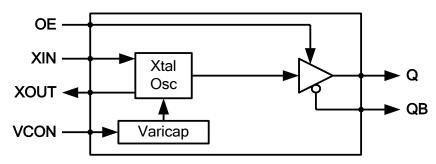
^{*} Internal 60KΩ pull-up resistor

OUTPUT ENABLE LOGIC PL586-58

OE State (Pad 4)	Output Buffers State
0 (Default)	Outputs Enabled
1	Outputs Tri-Stated

^{*} Internal $60K\Omega$ pull-down resistor

BLOCK DIAGRAM





PAD ASSIGNMENT

Pad #	Name	X (μm)*	Υ (μm)*	Description			
1	VCON	-194	-365	Voltage Control input			
2	XOUT	-372	-190	90 Crystal output connection			
3	XIN	-372	158	Crystal input connection			
4	VDD	-117	329	V _{DD} connection			
5	QB	140	315	Complementary LVPECL output			
6	Q	315	75	LVPECL output			
7	VSS	373	-127	GND connection			
8	OE	373	-373	Output enable pin. Internal pull up (-55) or pull down (-58).			

^{*} Note: Referenced to center of the die.

ELECTRICAL SPECIFICATIONS

1. Absolute Maximum Ratings

PARAMETERS	SYMBOL	MIN.	MAX.	UNITS
Supply Voltage	V_{DD}		4.6	V
Input Voltage, DC	Vı	V _{SS} -0.5	V _{DD} +0.5	V
Output Voltage, DC	Vo	V _{SS} -0.5	V _{DD} +0.5	V
Storage Temperature	Ts	-65	150	°C
Ambient Operating Temperature	T _A	-40	85	°C
HBM ESD Protection		2,000		V

Exposure of the device under conditions beyond the limits specified by Maximum Ratings for extended periods may cause permanent damage to the device and affect product reliability. These conditions represent a stress rating only, and functional operations of the device at these or any other conditions above the operational limits noted in this specification is not implied. *Operating temperature is guaranteed by design. Parts are tested to commercial grade only.



2. Voltage Control Crystal Oscillator

PARAMETERS	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
VCXO Stabilization Time *	T _{VCXOSTB}	From power valid			10	ms
VCXO Pullability *		XTAL $C_1 = 6.8$, $C_0/C_1 = 270$ $0V \le VCON \le V_{DD}$ (at 25°C)		± 120		ppm
VOXO Fullability		XTAL $C_1 = 3.7$, $C_0/C_1 = 480$ $0V \le VCON \le V_{DD}$ (at 25°C)		± 70		ppm
Varicap Control Range *		$VCON = 0$ to V_{DD}	0		3.3	V
Linearity *		$0.0V \le VCON \le 3.3V$		7		%
Lineanty		$0.3V \le VCON \le 3.0V$		2.5		%
VCON Input Impedance *		DC Input resistance	10			МΩ
VCON Modulation BW *		$0V \le VCON \le V_{DD}$, $-3dB$		30		kHz

Note: Parameters denoted with an asterisk (*) represent nominal characterization data and are not production tested to any specific limits.

3. Crystal Specifications

PARAMETERS	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Crystal Resonator Frequency	F _{XIN}	Fundamental Mode, AT cut	150		160	MHz
Crystal Loading Rating	C _{L (xtal)}	VCON = 1.65V		5		pF
Shunt Capacitance	C ₀				2.0	pF
Motional Capacitance	C ₁	Recommended for at least ±100ppm Frequency Pulling	5.5			fF
Decembered FCD	D	$C_0 \leq 2.0 pF$			10	Ω
Recommended ESR	R _E	$C_0 \leq 1.5 pF$			12	Ω

4. General Electrical Specifications

PARAMETERS	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Supply Current	I _{DD}	Standard LVPECL Loading (See LVPECL Levels Test Circuit, page 4)			50	mA
Operating Voltage	V_{DD}		2.97	3.3	3.63	V
Output Clock Duty Cycle		@ V _{DD} − 1.3V (See LVPECL Transition Time Waveform, page 4)	45	50	55	%
Short Circuit Current				±50		mA



5. Jitter Specifications

PARAMETERS	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Period Jitter RMS	At 155.52MHz, with capacitive		2.5		20
Period Jitter pk-to-pk	decoupling between V _{DD} and GND. Over 10,000 cycles		20		ps
Integrated Jitter RMS at 155.52MHz	Integrated 12 kHz to 20 MHz		90		fs

6. Phase Noise Specifications

PARAMETERS	FREQUENCY	@10Hz	@100Hz	@1kHz	@10kHz	@100kHz	@1MHz	@10MHz	UNITS
Phase Noise, relative to carrier	155.52MHz	-68	98	124	144	152	156	158	dBc/Hz

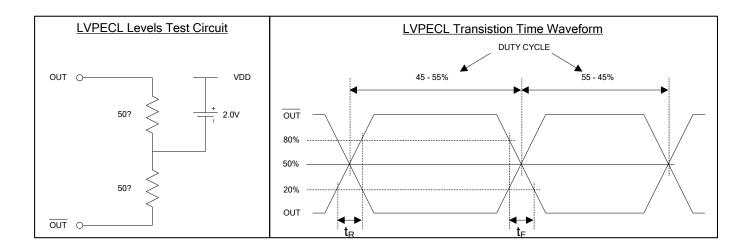
Note: Phase Noise measured at VCON = 0.3V to 3.0V.

7. LVPECL Electrical Characteristics

PARAMETERS	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Output High Voltage	V _{он}	$R_L = 50 \Omega \text{ to}$	V _{DD} – 1.025	V _{DD} - 0.950	$V_{DD} - 0.880$	V
Output Low Voltage	V _{OL}	(V _{DD} - 2V) (see figure)	V _{DD} - 1.810	V _{DD} - 1.700	V _{DD} - 1.620	V

8. LVPECL Switching Characteristics

PARAMETERS	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Clock Rise Time	t _r	@20/80% of output waveform		400	600	ps
Clock Fall Time	t _f	@80/20% of output waveform		400	600	ps





ORDERING INFORMATION

For part ordering, please contact our Sales Department: 2180 Fortune Drive, San Jose, CA 95131, USA

Tel: (408) 944-0800 Fax: (408) 474-1000

PART NUMBER

The order number for this device is a combination of the following: Part number, Package type and Operating temperature range

Part Number _	PL586-5X XX	
Packaging Option D = Die W = Wafer		Temperature Range C=Commercial (0°C to 70°C)

Order Number	Packaging
PL586-55DC PL586-58DC	Die – Waffle Pack
PL586-55WC PL586-58WC	Wafer

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